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SXB-2089Z

5MHz to 2500MHz MEDIUM POWER InGaP/GaAs HBT AMPLIFIER

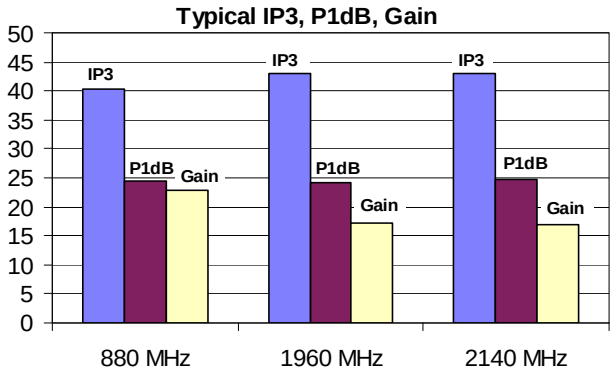
Package: SOT-89

Product Description

RFMD's SXB-2089Z amplifier is a high linearity InGaP/GaAs Heterojunction Bipolar Transistor (HBT) MMIC housed in a low-cost, surface-mountable plastic package. These amplifiers are specially designed for use as driver devices for infrastructure equipment in the 5MHz to 2500MHz Cellular, ISM, WLL, PCS, and W-CDMA applications. It's high linearity makes it an ideal choice for multi-carrier as well as digital applications.

Optimum Technology Matching® Applied

- ✓ GaAs HBT
- GaAs MESFET
- ✓ InGaP HBT
- SiGe BiCMOS
- Si BiCMOS
- SiGe HBT
- GaAs pHEMT
- Si CMOS
- Si BJT
- GaN HEMT
- RF MEMS



Features

- High OIP_3: +43dBm at 1960MHz
- P_{1dB}: 24dBm
- High Linearity/ACP Performance
- Robust 2000V ESD, Class 2
- SOT-89 Package

Applications

- PA Driver Amplifier
- IF Amplifier
- Cellular, PCS, ISM, WLL, W-CDMA

Parameter	Specification			Unit	Condition
	Min.	Typ.	Max.		
Small Signal Gain		25.0		dBm	450MHz
	21.5	23.0	24.5	dBm	880MHz
	15.5	17.0	21.5	dBm	1960MHz
		17.0		dBm	2140MHz
Input VSWR		1.1			450MHz
		1.4	2.5		880MHz
		1.6			1960MHz
		1.3			2140MHz
Output Power at 1dB Compression		24.0		dBm	450MHz
	23.0	24.5		dBm	880MHz and 1960MHz
		24.5		dBm	2140MHz
Third Order Intercept Point		40.0		dBm	450MHz
	38.0	41.0		dBm	880MHZ
	40.0	43.0		dBm	1960MHz
		43.0		dBm	2140MHz
Noise Figure		4.9		dB	450MHz
		4.5	6.0	dB	880MHz
		4.7		dB	1960MHz
		4.2		dB	2140MHz
Channel Power IS-95		16.0		dBm	450MHz, IS-95, -55dBc ACP
		16.3		dBm	880MHz, IS-95, -55dBc ACP
		15.5		dBm	1960MHz, IS-95, -55dBc ACP
		15.6		dBm	2140MHz, WCDMA, -50dBc ACP
Thermal Resistance		51.3		°C/W	junction - lead
Device Operating Current	120	135	150	mA	V_S=8v, R_{BIAS}=20Ω, V_{DEVICE}=5.2V

Test Conditions: T_A=25°C, Z_O=50Ω, P_{OUT} per tone=+11dBm, ToneSpacing=1MHz

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Absolute Maximum Ratings

Parameter	Rating	Unit
Device Current (I_{DQ})	190	mA
Device Voltage (V_D)	6	V
RF Input Power	20	dBm
Junction Temp (T_J)	+150	°C
Operating Temp Range (T_L)	-40 to +85	°C
Storage Temp	+150	°C
Operating Dissipated Power (quiescent)	1.0	W
ESD Rating - Human Body Model (HBM)	Class 2	
Moisture Sensitivity Level	MSL 2	

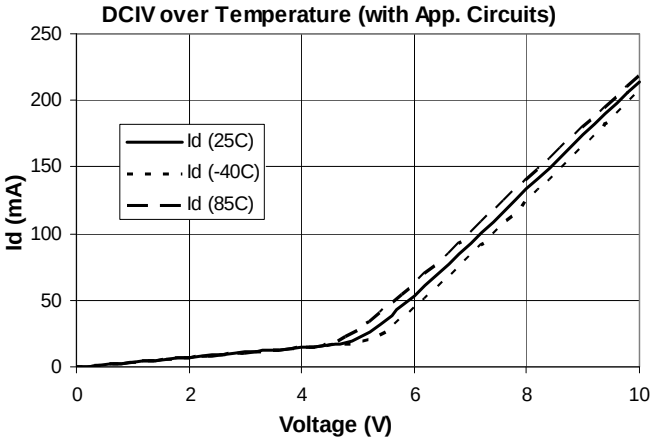
Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one.

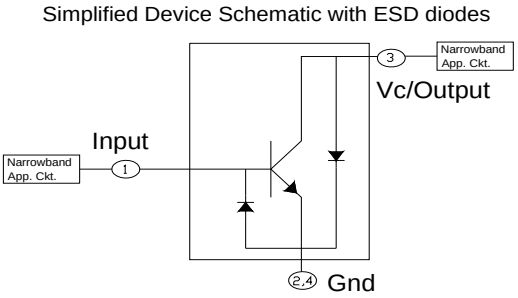
Bias Conditions should also satisfy the following expression:
$I_D V_D < (T_J - T_L)/R_{TH}$, j-l and $T_L = T_{LEAD}$

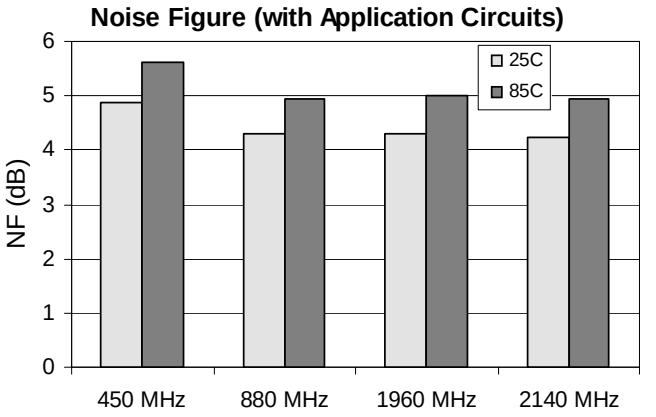
Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EUDirective2002/95/EC (at time of this document revision).







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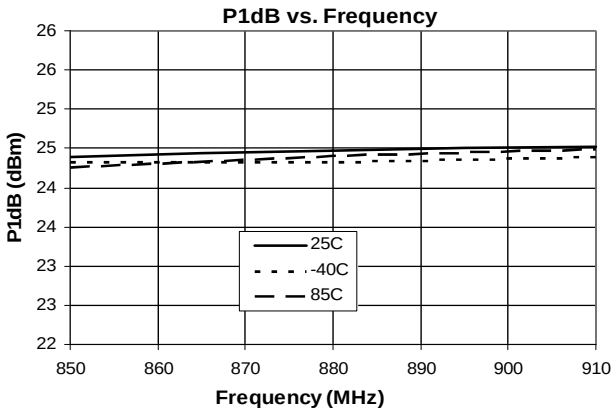
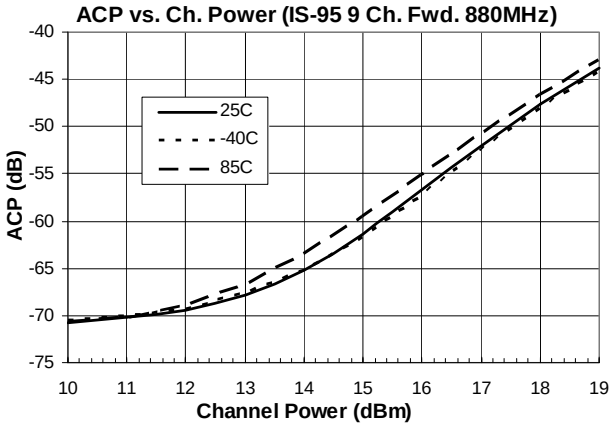
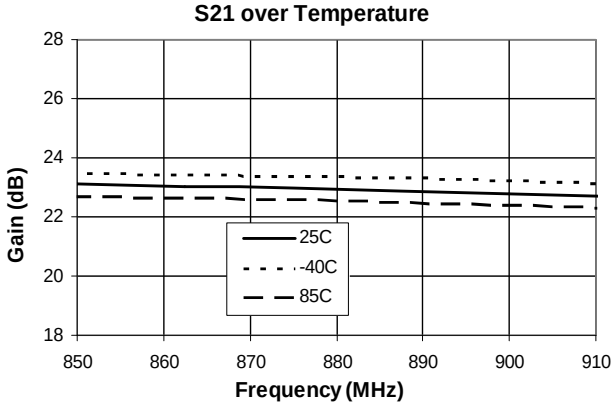
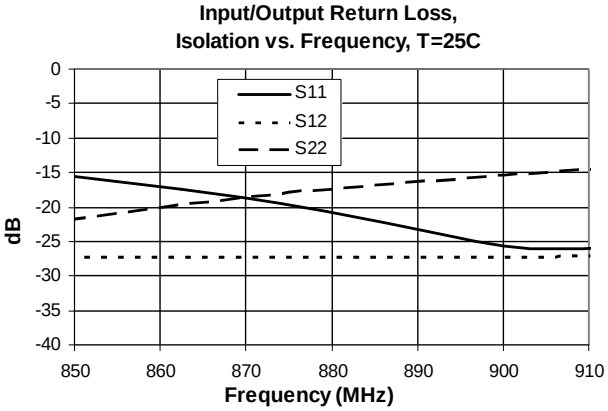
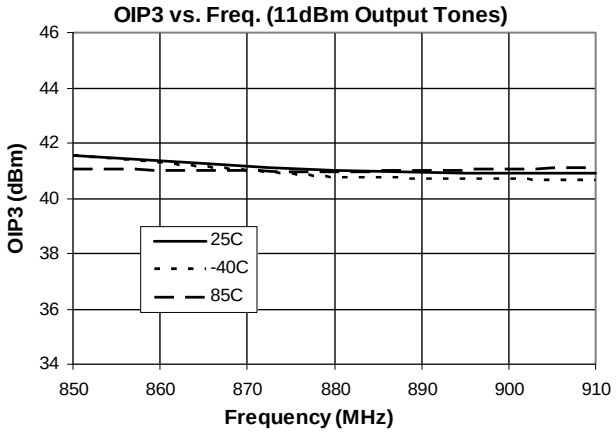
880 MHz Application Circuit Data, I_D=135mA, T=+25C, R_{Bias}=20 Ohm, V_S=8V

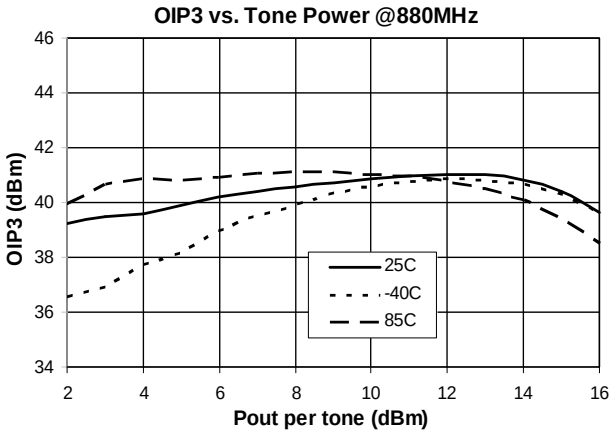




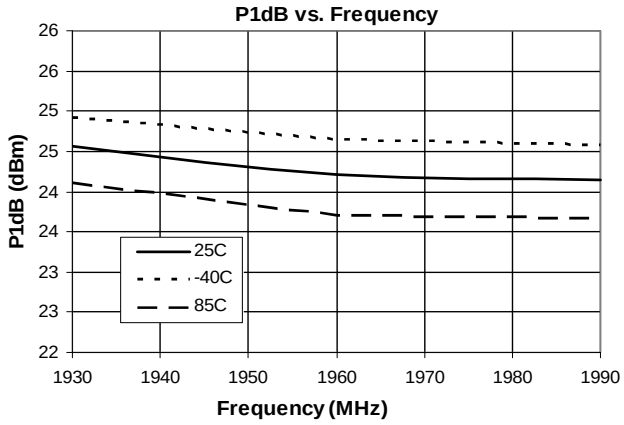


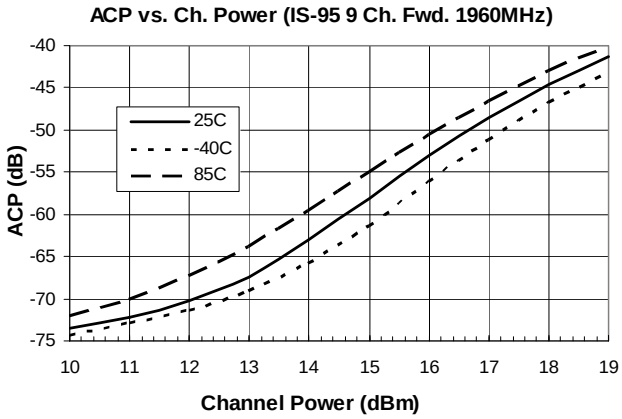


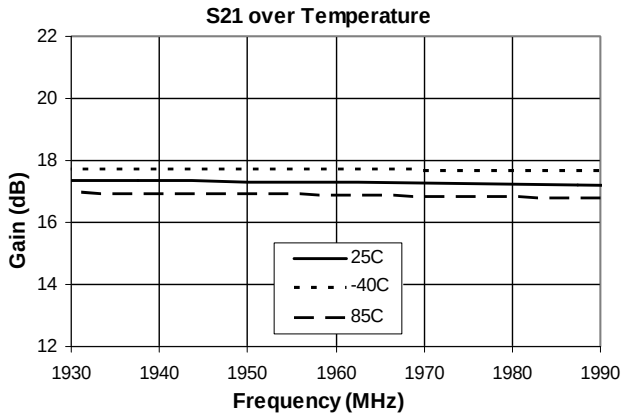


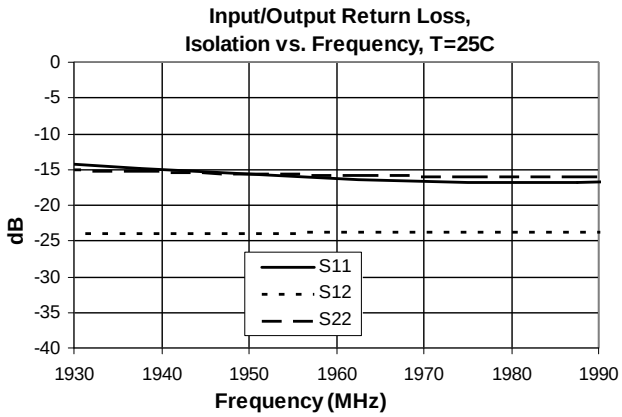


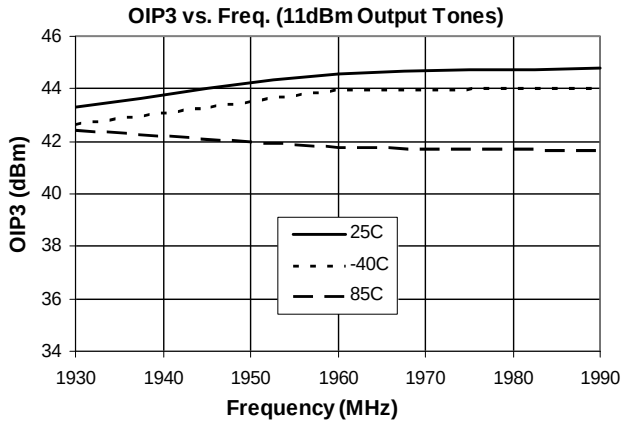
1960 MHz Application Circuit Data, I_D=135mA, T=+25C, R_{Bias}=20 Ohm, V_S=8V

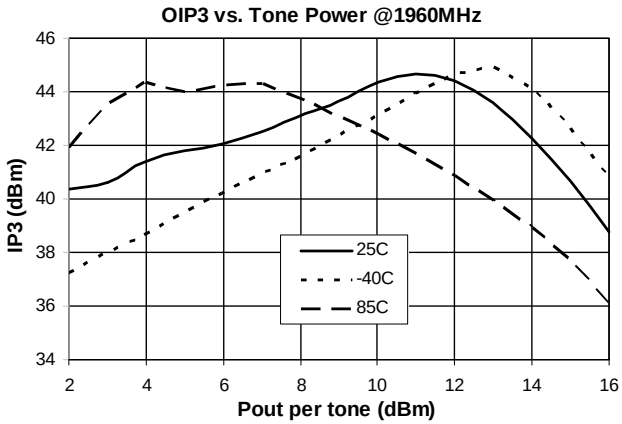












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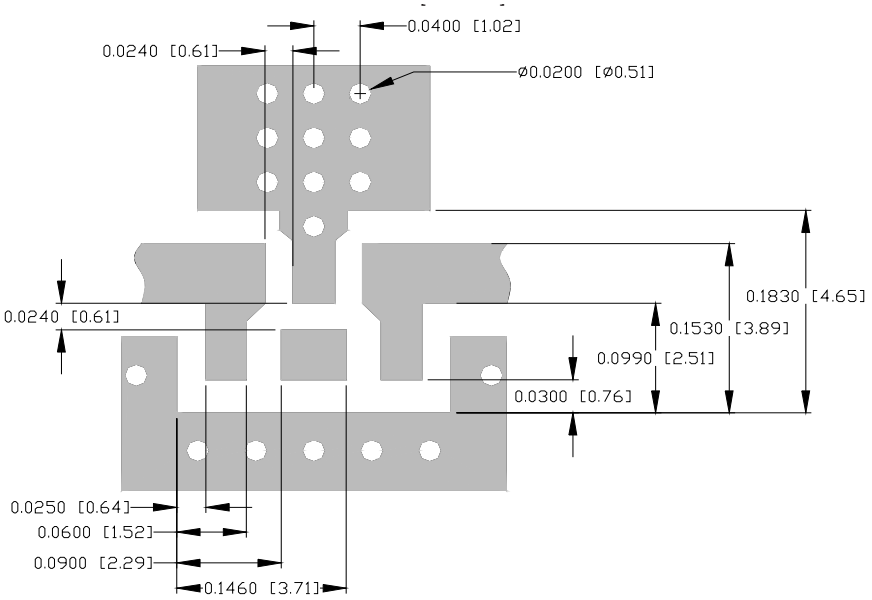
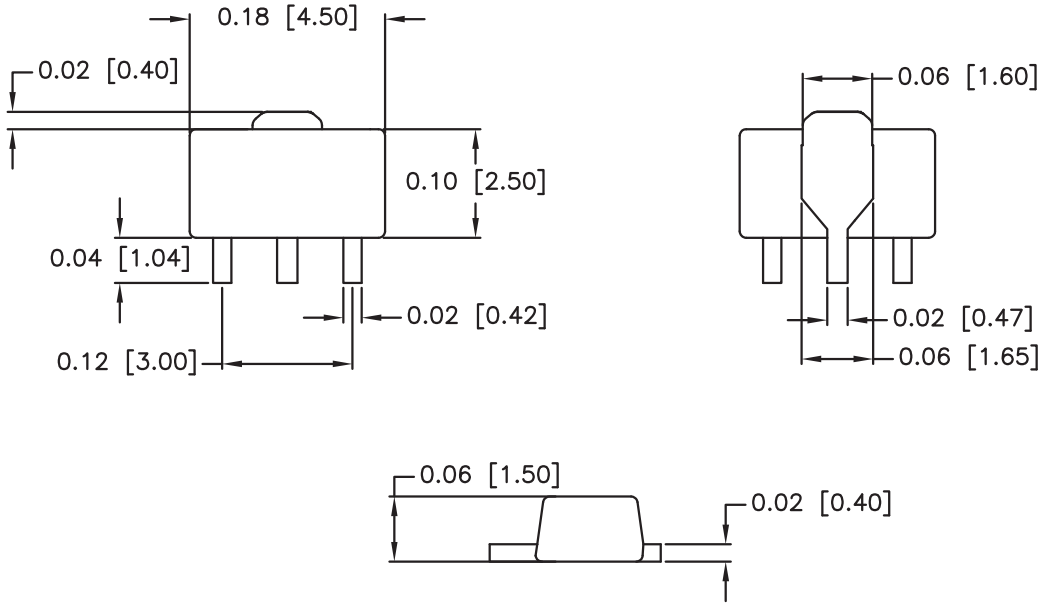
Pin	Function	Description
1	RF IN	RF input pin. This pin requires the use of an external DC blocking capacitor and matching components chosen for the frequency of operation.
2, 4	GND	Connection to ground. Use via holes for best performance to reduce lead inductance as close to ground leads as possible.
3	RF OUT/BIAS	RF output pin. This pin requires the use of an external DC blocking capacitor, choke, and matching components as shown in the Application Schematic.

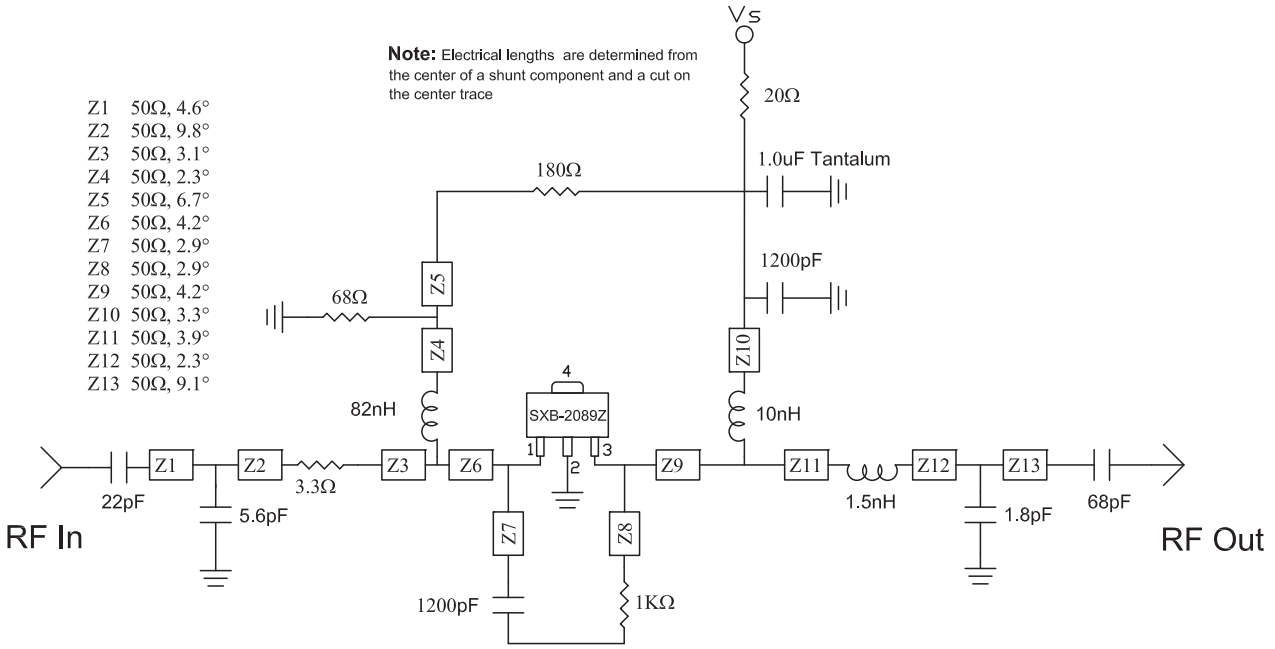
Suggested Pad Layout



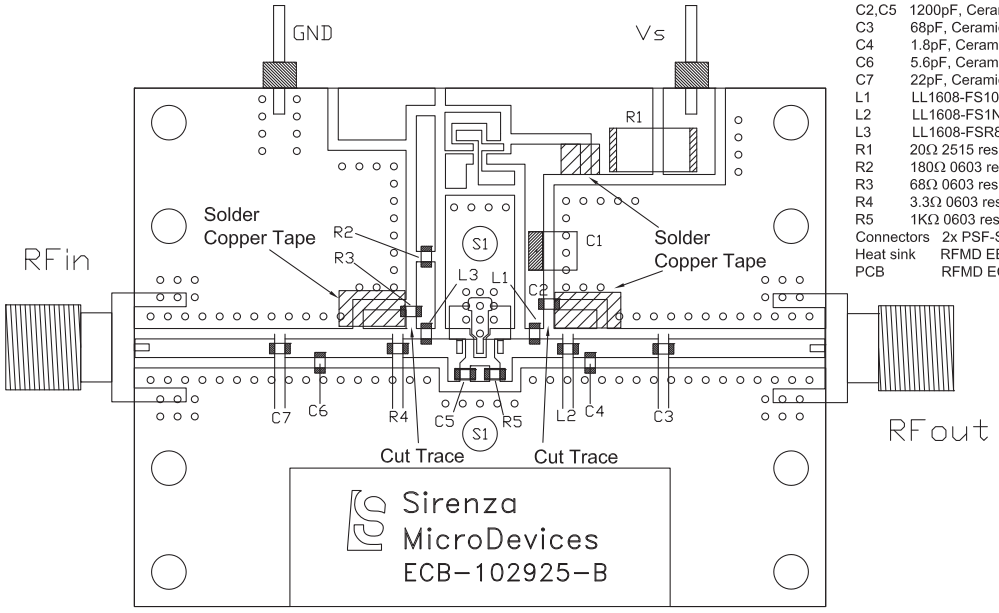
Package Drawing



880 MHz Application Schematic



Evaluation Board Layout and Bill of Materials



Bill of Materials

C1	1.0uF, Size A Tantulum Cap
C2,C5	1200pF, Ceramic 0603 Cap
C3	68pF, Ceramic 0603 Cap
C4	1.8pF, Ceramic 0603 Cap
C6	5.6pF, Ceramic 0603 Cap
C7	22pF, Ceramic 0603 Cap
L1	LL1608-FS10NJ Toko 10nH
L2	LL1608-FS1N5S Toko 1.5nH
L3	LL1608-FSR82NJ Toko 82nH
R1	20Ω 2515 res (1%)
R2	180Ω 0603 res (5%)
R3	68Ω 0603 res (5%)
R4	3.3Ω 0603 res (5%)
R5	1KΩ 0603 res (5%)
Connectors	2x PSF-S01-1mm GigaLane Co.
Heat sink	RFMD EEF-101216
PCB	RFMD ECB-102925-B

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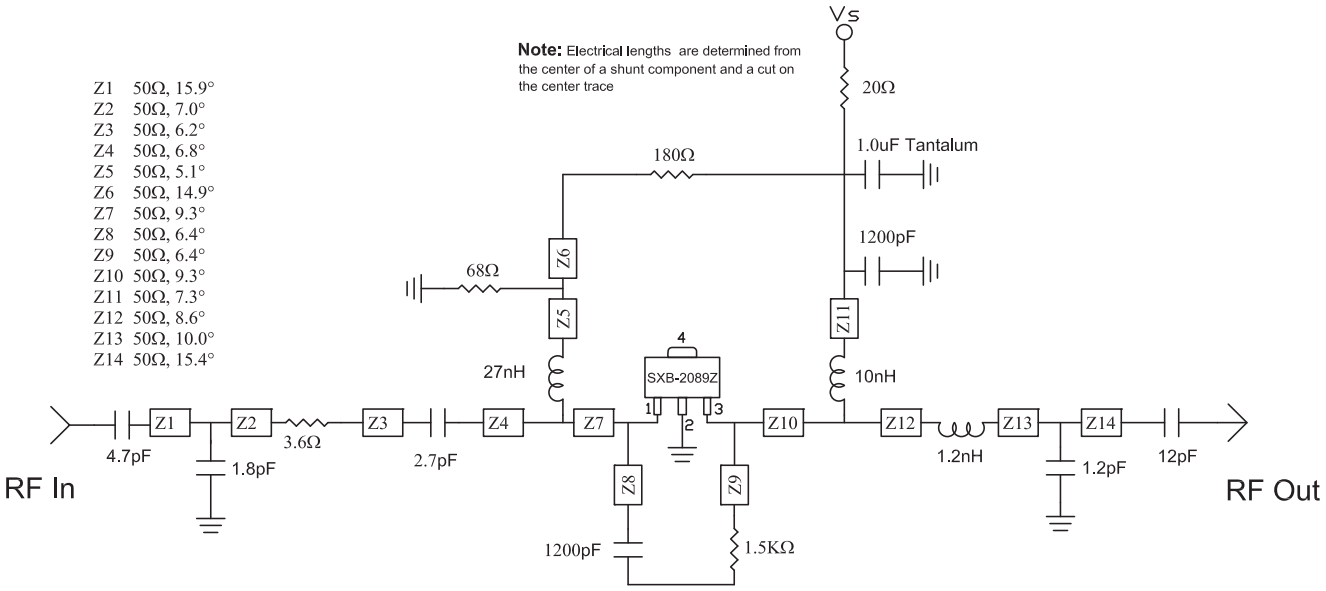
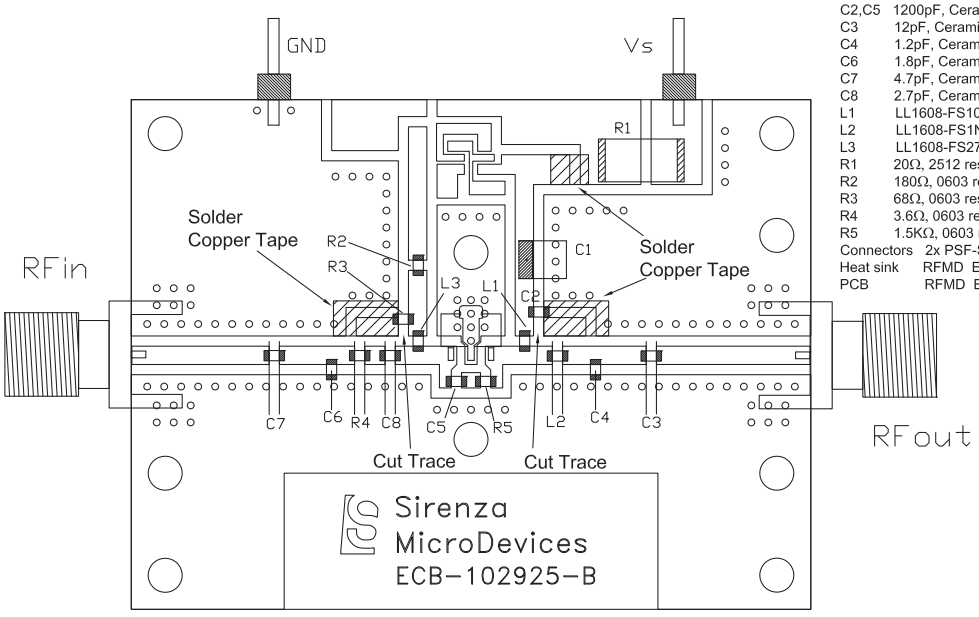
1960MHz Application Schematic



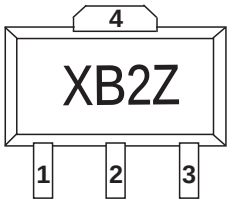
Evaluation Board Layout and Bill of Materials



Bill of Materials

C1	1.0uF, Size A Tantulum Cap
C2,C5	1200pF, Ceramic 0603 Cap
C3	12pF, Ceramic 0603 Cap
C4	1.2pF, Ceramic 0603 Cap
C6	1.8pF, Ceramic 0603 Cap
C7	4.7pF, Ceramic 0603 Cap
C8	2.7pF, Ceramic 0603 Cap
L1	LL1608-FS10NJ Toko 10nH
L2	LL1608-FS1N2S Toko 1.2nH
L3	LL1608-FS270JK Toko 27nH
R1	20Ω, 2512 res (1%)
R2	180Ω, 0603 res (5%)
R3	68Ω, 0603 res (5%)
R4	3.6Ω, 0603 res (5%)
R5	1.5KΩ, 0603 res (5%)
Connectors	2x PSF-S01-1mm GigaLane Co.
Heat sink	RFMD EEF-101216
PCB	RFMD ECB-102925-B

Part Identification



Alternate marking is SXB2089Z on line 1 with Trace Code on line 2.

Ordering Information

Part Number	Reel Size	Devices/Reel
SXB-2089Z	7”	1000

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